

**•General Description**

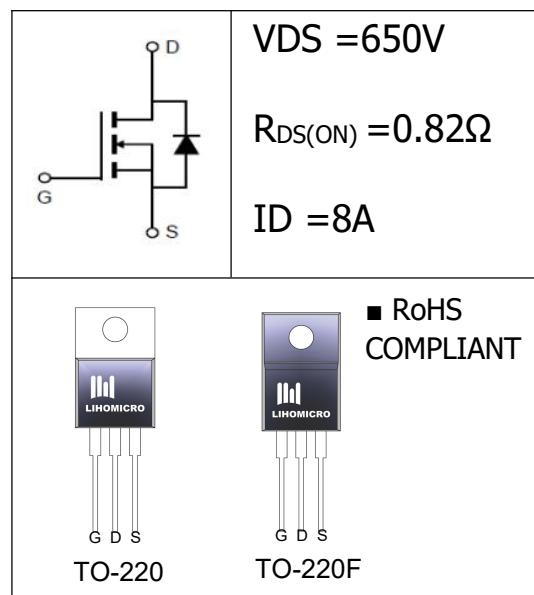
The Power MOSFET LH8N65EA has the low  $R_{DS(on)}$ , low gate charge, fast switching and excellent avalanche characteristics. This device offers extremely fast and robust body diode, and is suitable for telecom and power supplies.

**•Features**

- Low Thermal Resistance
- Fast Switching
- High Input Resistance

**•Application**

- LED/LCD/PDP TV and monitor Lighting
- Power Supplies


**•Ordering Information:**

|                                       |                         |                       |
|---------------------------------------|-------------------------|-----------------------|
| Part number                           | LH8N65EA                | LH8N65EA              |
| Package                               | TO-220F                 | TO-220                |
| Basic ordering unit (pcs)             | 1000                    | 1000                  |
| Normal Package Material Ordering Code | LH8N65EAF-T0220F-TU     | LH8N65EAT-T0220-TU    |
| Halogen Free Ordering Code            | LH8N65EAF-T0220F-TU -HF | LH8N65EAT-T0220-TU-HF |

**•Absolute Maximum Ratings (TC = 25°C)**

| PARAMETER   | SYMBOL     | Value       |             | UNIT |
|---|------------|-------------|-------------|------|
| Drain-Source Breakdown Voltage  | $BV_{DSS}$ | 650         |             | V    |
| Gate-Source Voltage   | $V_{GS}$   | $\pm 30$    |             | V    |
| Continuous Drain Current<br>TC = 25°C<br>TC = 100°C                   | $I_D$      | 8           |             | A    |
|   |            | 3.5         |             |      |
| Pulsed drain current<br>(TC = 25°C, tp limited by Tjmax) <sup>1</sup> | $I_{DM}$   | 32          |             | A    |
| Avalanche Current <sup>1</sup>  | $I_{AR}$   | 8           |             | A    |
| Single Pulse Avalanche Energy <sup>2</sup>                            | $E_{AS}$   | 230         |             | mJ   |
| Repetitive Avalanche Energy <sup>1</sup>                              | $E_{AR}$   | 14          |             | mJ   |
| Power Dissipation(TC=25°C)  | $P_D$      | TO-220F: 40 | TO-220: 150 | W    |
| Junction Temperature  | $T_J$      | -55~+150    |             | °C   |
| Storage Temperature   | $T_{STG}$  | -55~+150    |             | °C   |

**• Electronic Characteristics**

| PARAMETER                               | SYMBOL       | TEST CONDITION                                  | MIN | TYP  | MAX       | UNIT     |
|---|--------------|---|-----|------|-----------|----------|
| Drain-Source Breakdown Voltage          | $BV_{DSS}$   | $V_{GS} = 0V, I_D = 250\mu A$                   | 650 | --   | --        | V        |
| Gate Threshold Voltage                  | $V_{GS(TH)}$ | $V_{DS} = V_{GS}, I_D = 250\mu A$               | 2.0 | --   | 4.0       | V        |
| Drain-source On Resistance <sup>3</sup> | $R_{DS(ON)}$ | $V_{GS} = 10V, I_D = 4A$                        | --  | 0.82 | 1.0       | $\Omega$ |
| Drain-Source Leakage Current            | $I_{DSS}$    | $V_{DS} = 650V, V_{GS} = 0V, T_J = 25^\circ C$  | --  | --   | 1         | uA       |
|   |              | $V_{DS} = 480V, V_{GS} = 0V, T_J = 125^\circ C$ | --  | --   | 100       |          |
| Gate-Source Leakage Current             | $I_{GSS}$    | $V_{GS} = \pm 30$                               | --  | --   | $\pm 100$ | nA       |
| Forward Transconductance <sup>3</sup>   | $g_{fs}$     | $V_{DS} = 15V, I_D = 4A$                        | --  | 3    | --        | S        |
| Input Capacitance                       | $C_{iss}$    | $V_{GS} = 0V, V_{DS} = 25V, f = 1.0MHz$         | --  | 1450 | --        | pF       |
| Output Capacitance                      | $C_{oss}$    |   | --  | 108  | --        |          |
| Reverse transfer Capacitance            | $C_{rss}$    |   | --  | 19   | --        |          |
| Turn-Off Delay Time <sup>3</sup>        | $T_{d(off)}$ | $V_{DD} = 300V, I_D = 8A, R_G = 25\Omega$       | --  | 81   | --        | ns       |
| Total Gate Charge <sup>3</sup>          | $Q_g$        | $I_D = 8A, V_{DS} = 520V, V_{GS} = 10V$         | --  | 31.6 | 60        | nC       |
| Gate-to-Source Charge <sup>3</sup>      | $Q_{gs}$     |   | --  | 7.4  | 15        |          |
| Gate-to-Drain Charge <sup>3</sup>       | $Q_{gd}$     |   | --  | 11   | 20        |          |
| Continuous Diode Forward Current        | $I_S$        |   | --  | --   | 8         | A        |
| Pulsed Diode Forward Current            | $I_{SM}$     |   | --  | --   | 32        | A        |
| Diode Forward Voltage                   | $V_{SD}$     | $T_J = 25^\circ C, I_S = 8A, V_{GS} = 0V$       | --  | --   | 1.4       | V        |
| Reverse Recovery Time <sup>3</sup>      | $trr$        | $I_f = I_S, dI_f/dt = 100A/\mu s$               | --  | 365  | --        | ns       |
| Reverse Recovery Charge <sup>3</sup>    | $Q_{rr}$     |   | --  | 3.4  | --        | $\mu C$  |

**• Thermal Characteristics**

| PARAMETER                           | SYMBOL     | MAX     |        | UNIT |
|-------------------------------------|------------|---------|--------|------|
|                                     |            | TO-220F | TO-220 |      |
| Thermal Resistance Junction-case    | $R_{thJC}$ | 3.13    | 0.9    | °C/W |
| Thermal Resistance Junction-ambient | $R_{thJA}$ | 62.5    | 62.5   | °C/W |

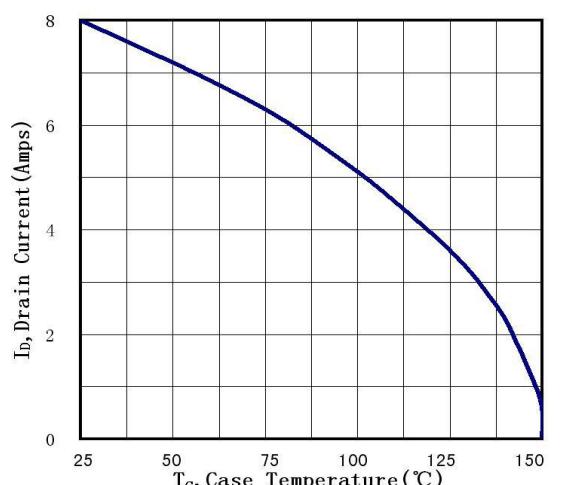
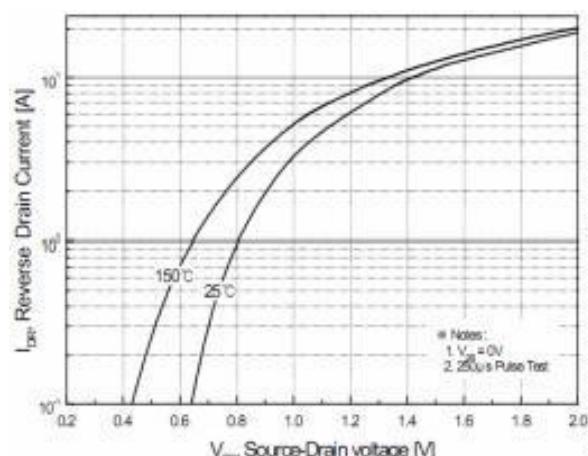
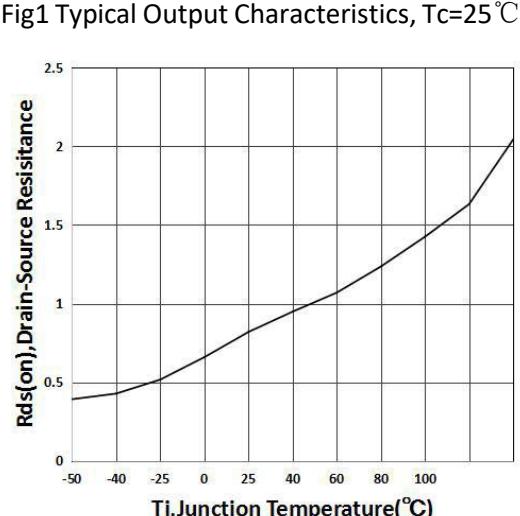
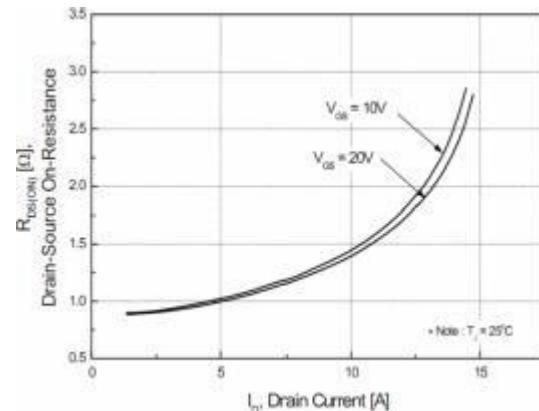
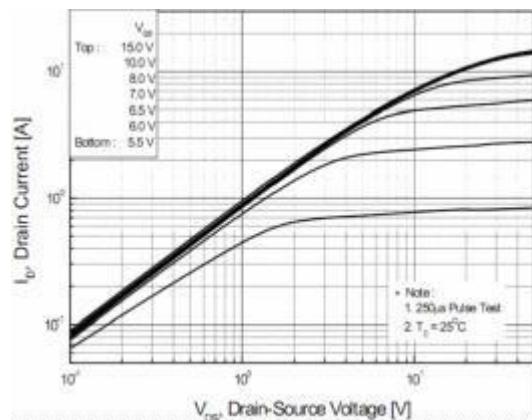
Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2.  $I_{AS} = 8A, V_{DD} = 50V, R_G = 25\Omega, L = 10\mu H$ , Starting  $T_J = 25^\circ C$

3. Pulse Test : Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$

•Typical Characteristics



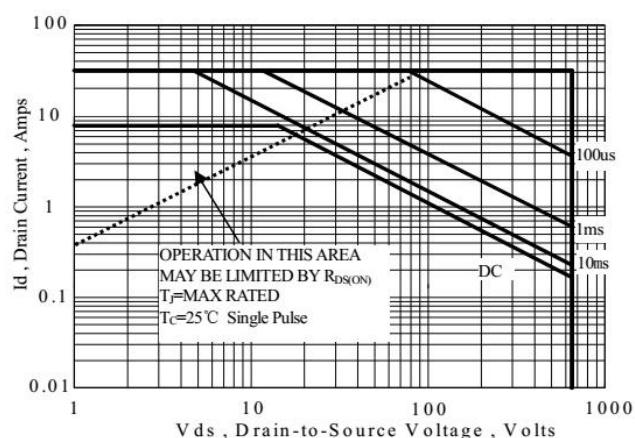
**•Typical Characteristics(cont.)**


Fig6 Maximum Safe Operating Area (TO-220)

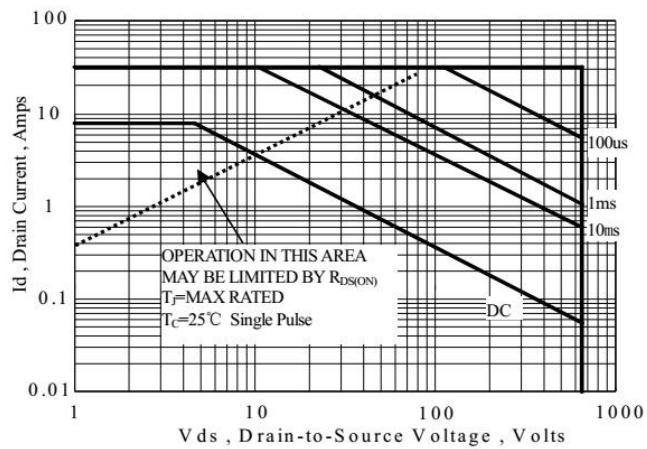
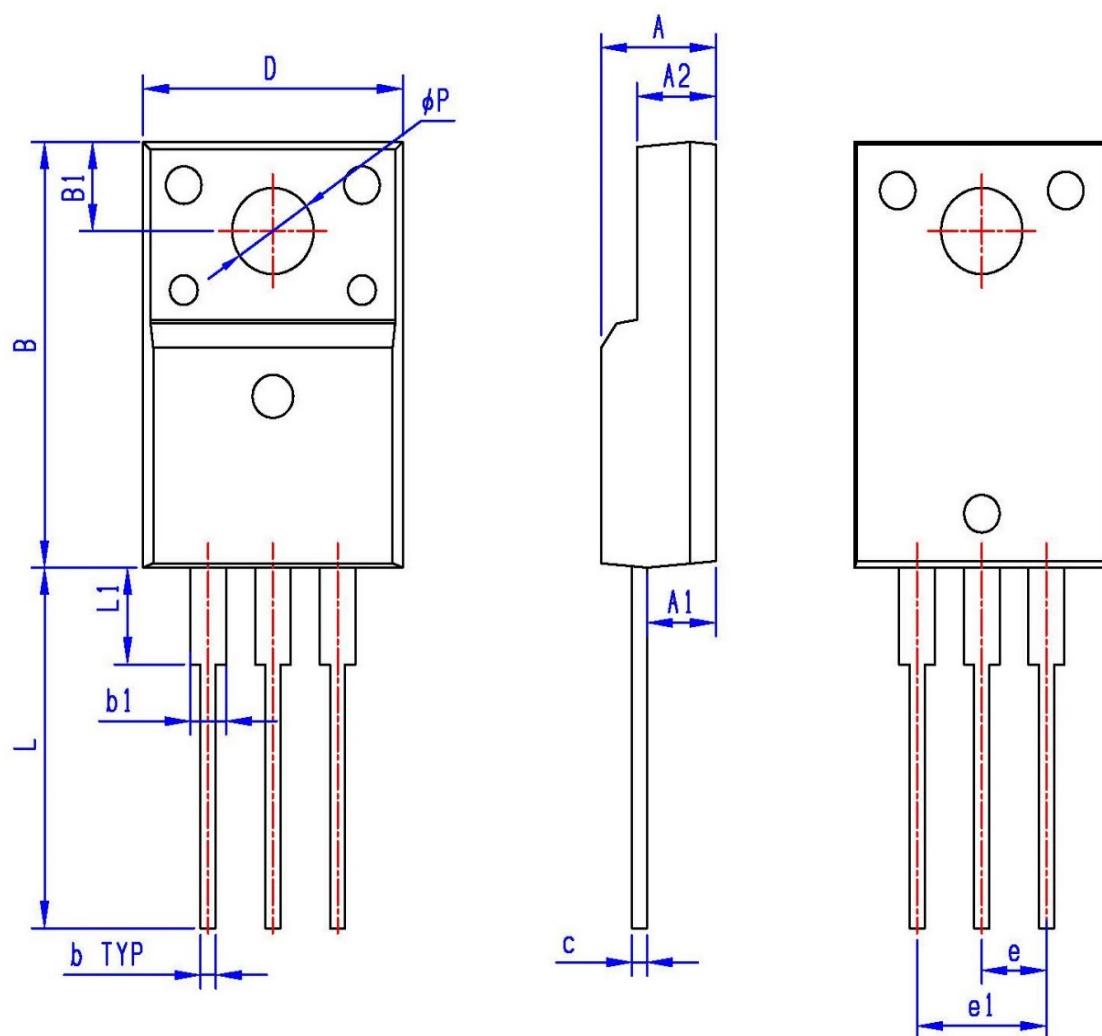


Fig7 Maximum Safe Operating Area (TO-220F)

**•Dimensions (TO-220F)**

UNIT:mm

| SYMBOL | min   | max   | SYMBOL | min   | max   |
|--------|-------|-------|--------|-------|-------|
| A      | 4.40  | 4.90  | B1     | 2.90  | 3.70  |
| A1     | 2.40  | 3.00  | e      | 2.40  | 2.70  |
| A2     | 2.30  | 3.00  | e1     | 4.95  | 5.25  |
| b      | 0.60  | 0.90  | L      | 12.40 | 14.20 |
| b1     | 1.10  | 1.70  | L1     | 2.40  | 3.40  |
| c      | 0.40  | 0.70  | øP     | 2.90  | 3.50  |
| D      | 9.80  | 10.60 |        |       |       |
| B      | 15.40 | 16.40 |        |       |       |



**•Dimensions (TO-220)**

UNIT:mm

| SYMBOL | min   | max   | SYMBOL | min   | max   |
|--------|-------|-------|--------|-------|-------|
| A      | 4.25  | 4.85  | B1     | 2.60  | 3.00  |
| A1     | 2.30  | 3.00  | e      | 2.40  | 2.70  |
| A2     | 1.20  | 1.40  | e1     | 4.95  | 5.25  |
| b      | 0.60  | 0.90  | L      | 12.60 | 14.40 |
| b1     | 1.10  | 1.70  | L1     | 2.40  | 4.00  |
| c      | 0.40  | 0.70  | øP     | 3.50  | 3.90  |
| D      | 9.80  | 10.60 |        |       |       |
| B      | 15.20 | 16.20 |        |       |       |

